Lifetime measurement and new Photonis sensor

ERLANGEN CENTRE FOR ASTROPARTICLE

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PANDA Meeting Darmstadt, December 06. 2016

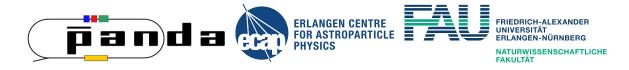


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New high QE Photonis sensor XP85012 9002085

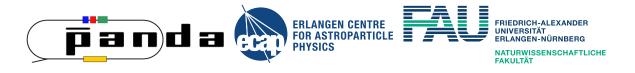


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Photonis XP85012 9002085 (25µm)

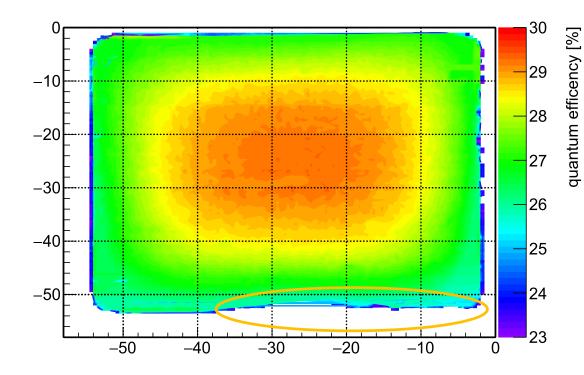
- 25µm MCP-PMT (no ALD coating)
- New developed photocathode material
- 10⁶ Gain at 1600V

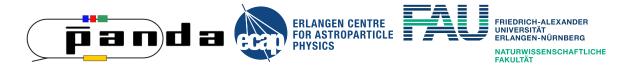


QE scan blue laser (372nm) Photonis 9002085

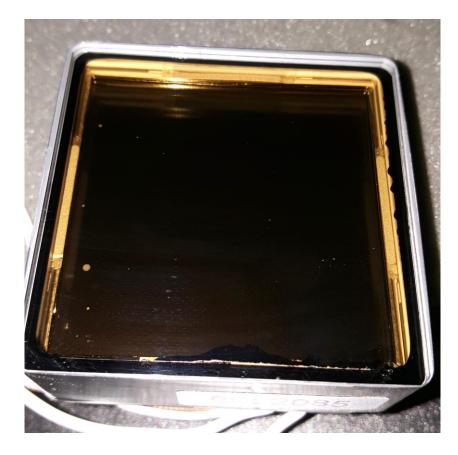
- QE uniform over surface (±2%)
- Higher QE towards middle of the sensor

 Marked area has reflective coating under window glass Quantum Efficiency - Photonis XP85012/ 9002085



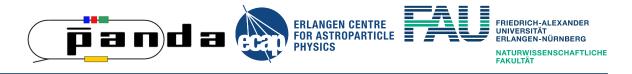


Photonis XP85012 9002085 (25µm)



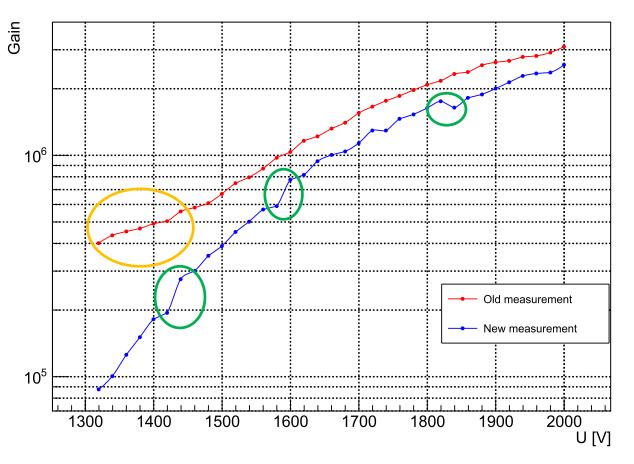
• Sealing material



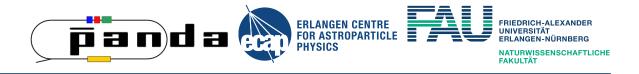


Gain Photonis 9002085

- Old measurement:
 - Taken when sensor was received
 - Threshold problems
- New measurement:
 - Taken without threshold
 - Jumps when histogram range adjusted
 - overall lower gain
 - Maybe other pixel or integrated charge effect



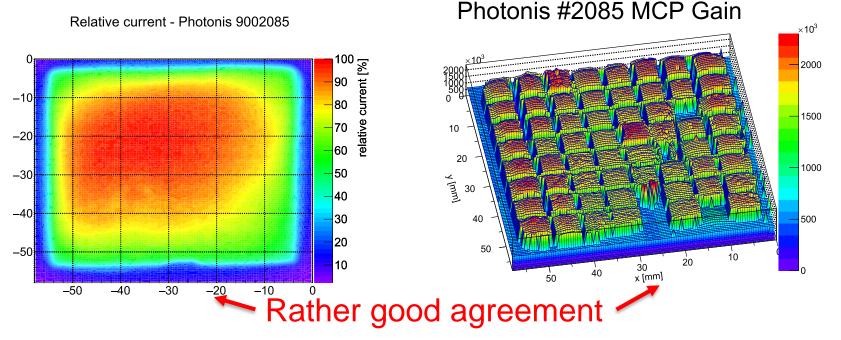
GAIN 9002085



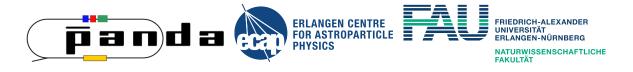
Gain scans Photonis 9002085

- Current of shortened anodes measured at 1.6kV (no single Photons)
- Relative gain
- Folded with QE

- Gain of pulse signals (single Photons)
- Measured at 1.6 kV
- 10x amplifiers LeCroy 612A

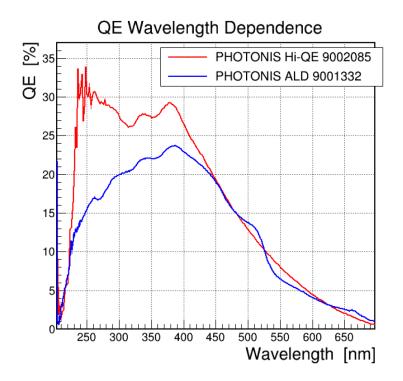


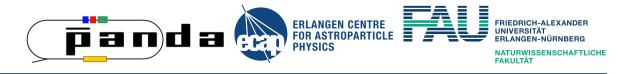
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Wavelength dependent QE Photonis 9002085

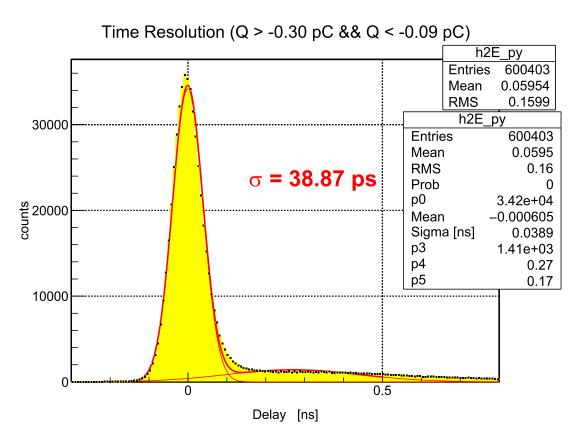
- Higher QE in area from 250nm to 450nm
- Max QE of 29% at 380nm
- Very promising

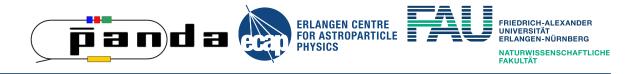




Time resolution Photonis 9002085

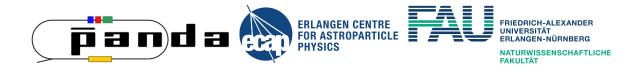
- Measured with red laser and Oscilloscope
- 1.6 kV (10⁶ Gain)
- 200x Fast amp ORTEC FTA 820 (impedance matched splitter)
- TDC threshold at 50 mV
- Time walk corrected
- Typical sigma for 25 µm
- Tail seems to be caused by sensor, same results with red and blue laser



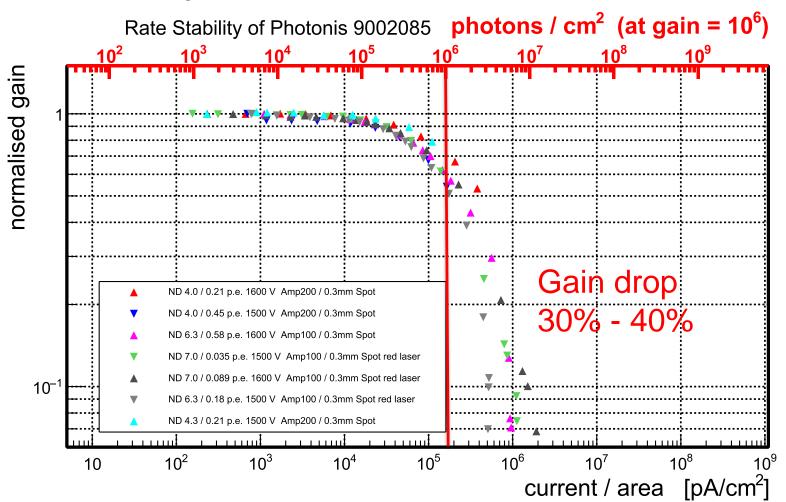


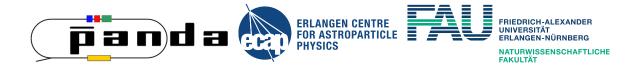
Rate stability Photonis 9002085

- Illuminated with single photons and laser spot of 3mm diameter on Pixel 44
- Amplified with 200x Fast amp ORTEC FTA 820 (impedance matched splitter for TDC)
- TDC threshold set to 20 mV
- Calculate p.e. count by ratio of pedestal and signal counts (Poisson mean)
- Charge calculated by multiplying average charge per event with laser frequency then normed to 1cm² illuminated area
- Measured multiple curves (different filters and supply Voltages) to get different Poisson means
- All curves should show the same behavior



Rate stability Photonis 9002085





Photonis 2085 (25µm)

- No ALD coating
- Low supply voltage for 10⁶ Gain
 - Photonis sensors in lifetime measurement need at least 2kV
- Low rate stability compared to other Photonis MCP-PMTs
 - Could be different to other Photonis tubes because of missing ALD coating
- Otherwise good performance
- Need to test also high QE tubes with ALD and 10µm pores

Results of latest measurements



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Data from January 23. 2017 Illumination Overview QE (all sensors with ALD)

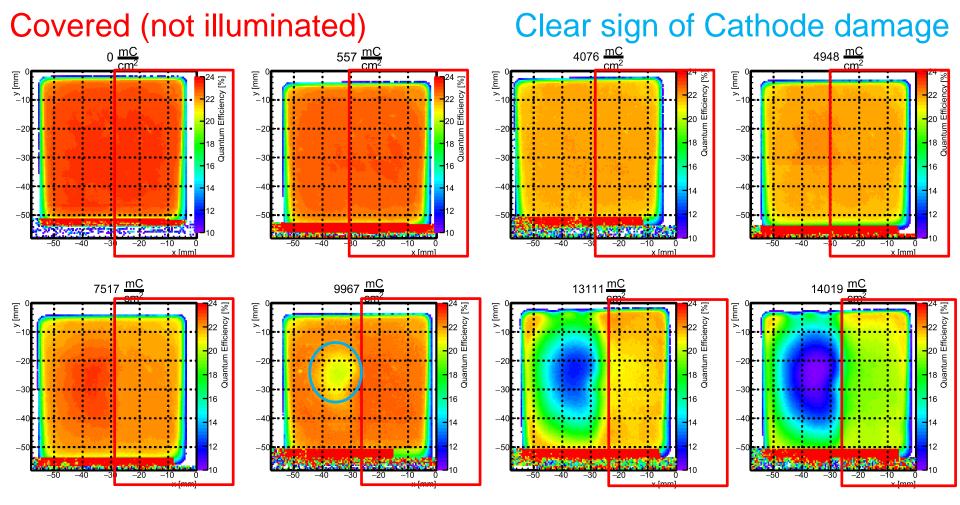
Film between MCP Two ALD layers Film in front of first MCP

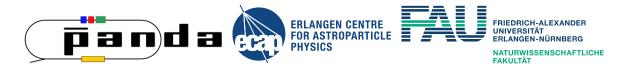


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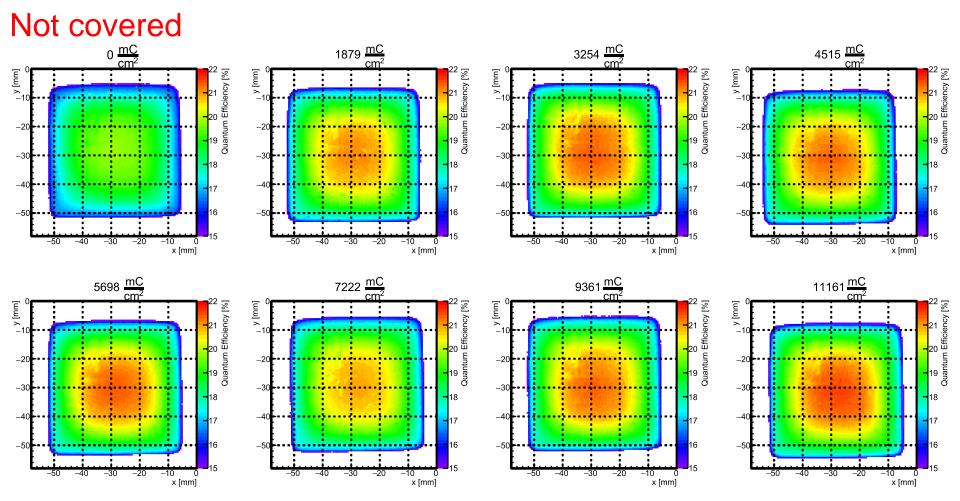


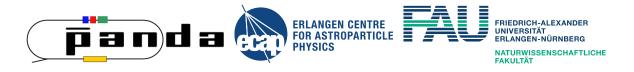
QE scan of Photonis 9001332 (ALD)





QE scan of Photonis 9001393-URD (ALD)





QE scan of Hamamatsu KT0001 (ALD)

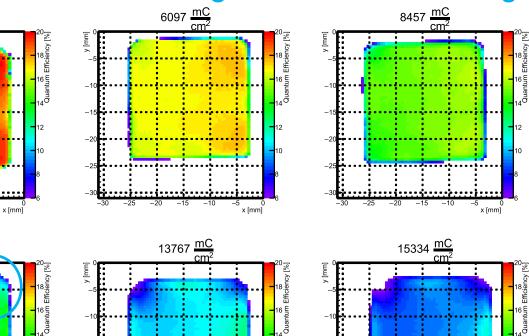
843 <u>mC</u>

cm

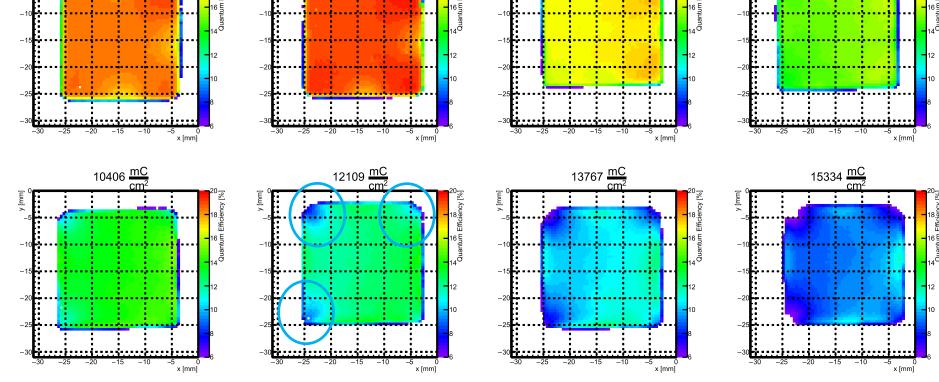
Not covered

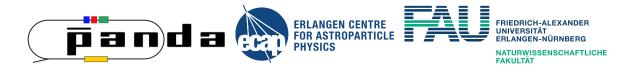
 $0 \frac{mC}{cm^2}$

n Efficien



Clear sign of Cathode damage





x (mm)

QE scan of Hamamatsu KT0002 (ALD)

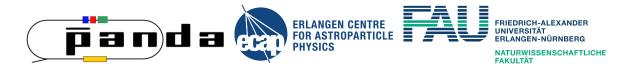
Clear sign of Cathode damage Not covered 2312 <u>mC</u> 3571 <u>mC</u> cm² 4933 mC cm² 143 mC cm² cm 4 10 12 0 Quantum Efficiency & Efficiency Efficie 8 Efficies 6 <u>E</u> 16 Duantum 14 4đ -20 x [mm] x [mm] x [mm] x [mm] 7605 <u>mC</u> 6011 mC 9856 mC 11848 <u>mC</u> Ē Quantum Efficiency [% Efficie B Efficies Efficies 16 Duantum 40 ٩ð

x [mm]

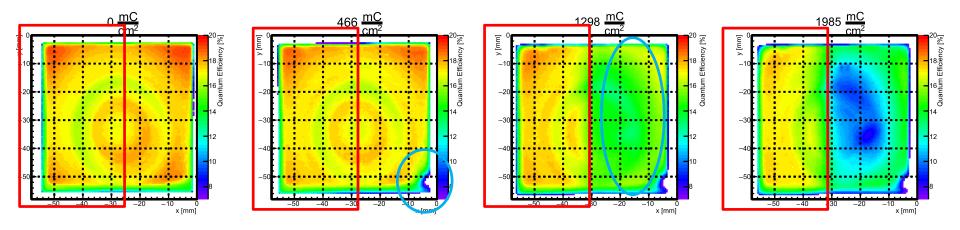
x [mm]

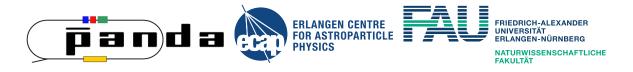
19

x [mm]

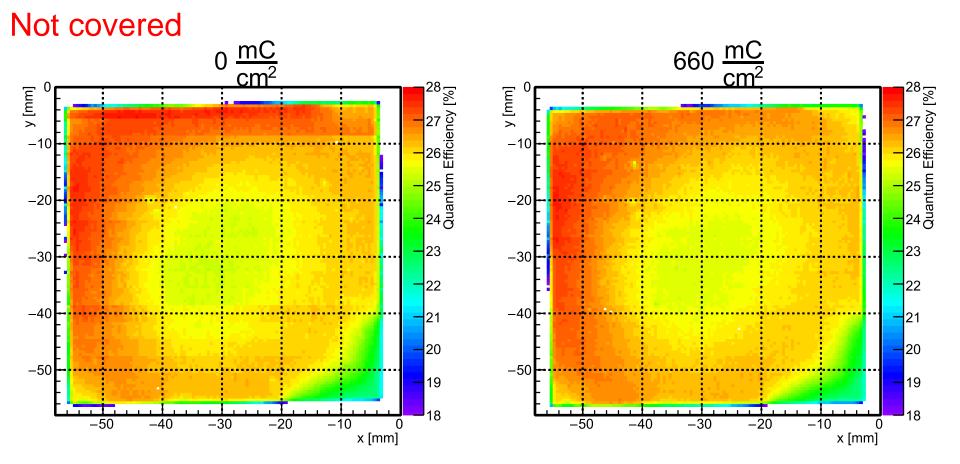


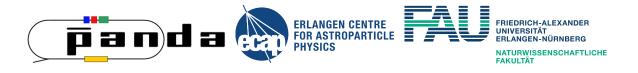
QE scan of Hamamatsu JS0022 (8x8, ALD)Covered (not illuminated)Clear sign of Cathode damage



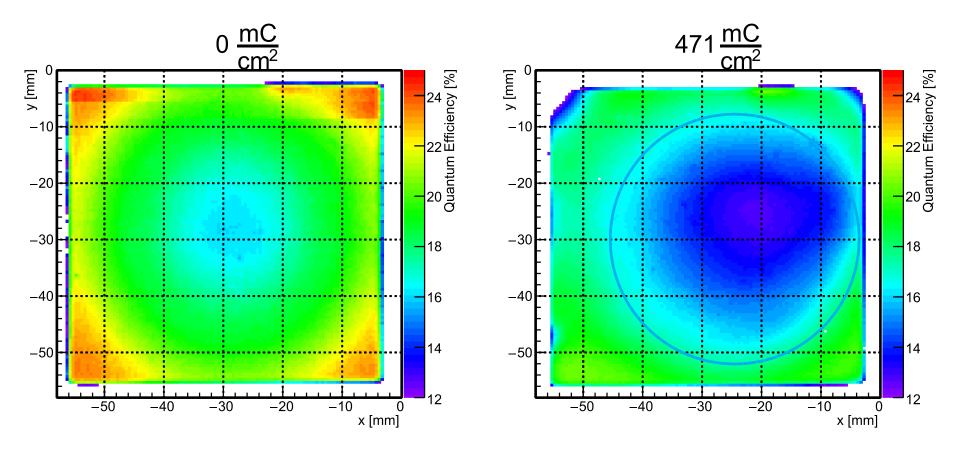


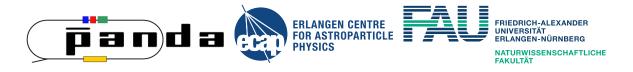
QE scan of Hamamatsu JS0035 (8x8, ALD)



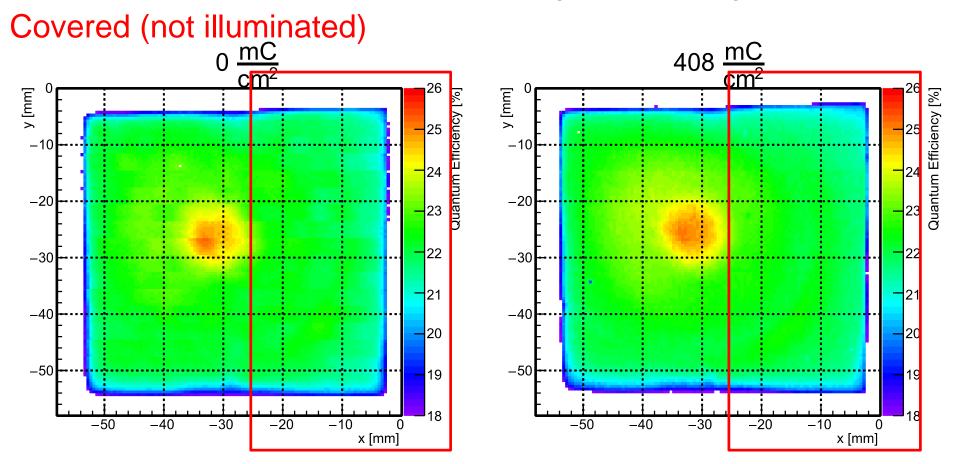


QE scan of Hamamatsu JS0018 (6x128, ALD)Not coveredClear sign of Cathode damage

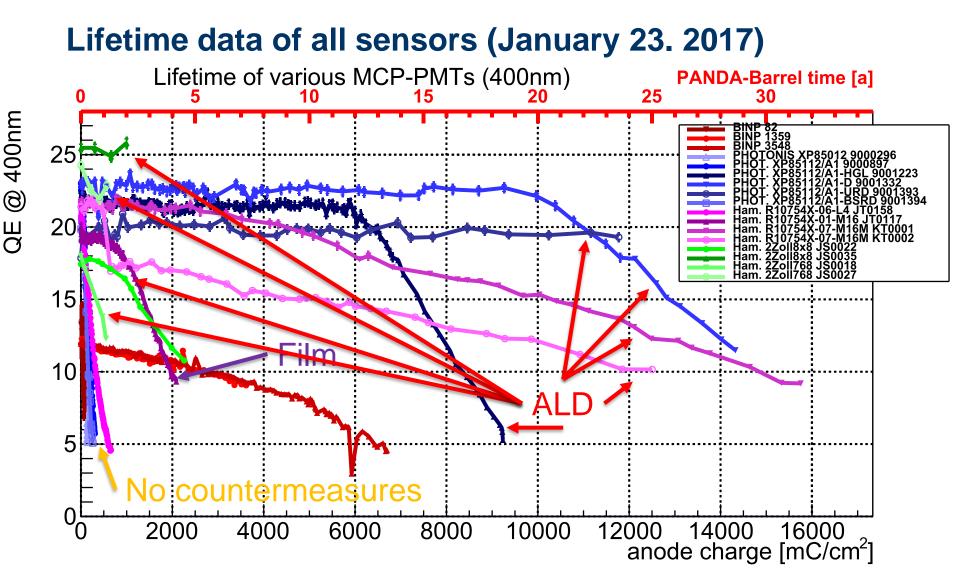


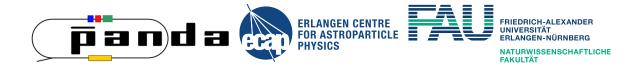


QE scan of Hamamatsu JS0027 (6x128, ALD)









Summary and outlook

- Promising results with new Photonis prototype
 - 10⁶ Gain at 1600V (relative low supply voltage)
 - High QE in region 250nm to 450nm
 - Rather uniform QE and gain distribution over sensor surface
 - Good time resolution (for 25µm pores)
- Trend of better performance with newer Hamamatsu 2 inch sensors
 - Better homogeneity of photo cathode surface (QE)
 - No PC damage seen yet (JS0027 and JS0035)

GEFORDERT VOM



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Thank you for your attention!

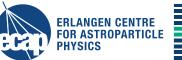
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